

N-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (mΩ) (Typ.)	I _D (A) ^a	Q _g (Typ.)
20	130 at V _{GS} = 4.5 V	1.8	0.85 nC
	190 at V _{GS} = 2.5 V		

FEATURES

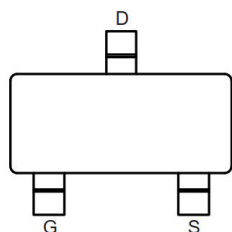
- DT-Trench Power MOSFET
- Suit for 1.5V Gate Drive Applications
- Fast switching
- ESD Protected

APPLICATIONS

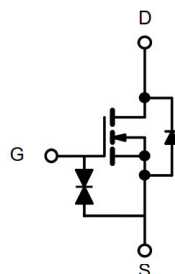
- Load Switch
- Battery Protection


RoHS
 COMPLIANT

SOT-23 Pin Configuration



Top View



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	± 8	
Continuous Drain Current (T _J = 150 °C)	I _D	T _C = 25 °C	A
		T _C = 100 °C	
Pulsed Drain Current	I _{DM}	7.2	W
Maximum Power Dissipation ^a	P _D	T _C = 25 °C	
		T _C = 100 °C	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-Ambient (PCB Mount) ^{b,d}	R _{thJA}	166	°C/W

Notes:

- T_C = 25 °C.
- Surface mounted on 1" x 1" FR4 board.
- t = 5 s.
- Maximum under steady state conditions is 200C/W.

SPECIFICATIONS ($T_J = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

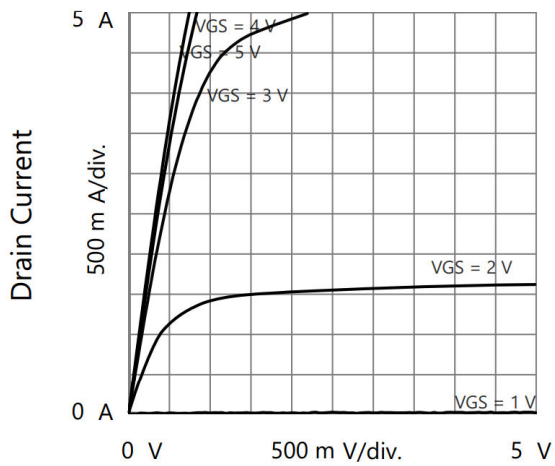
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	20	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	0.35	-	1	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V	-	-	± 10	μA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V	-	-	1	μA
On-State Drain Current ^a	I _{D(on)}	V _{DS} ≥ 5 V, V _{GS} = 10 V	1.8	-	-	A
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 0.6 A	-	130	160	mΩ
		V _{GS} = 2.5 V, I _D = 0.6 A	-	190	250	
Forward Transconductance ^a	g _{fs}	V _{DS} = 5 V, I _D = 0.6 A	-	1.5	-	S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 10 V, f = 1MHz	-	47	-	pF
Output Capacitance	C _{oss}		-	15	-	
Reverse Transfer Capacitance	C _{rss}		-	8.5	-	
Total Gate Charge ^c	Q _g	V _{DS} = 10 V, V _{GS} = 4.5 V, I _D = 0.6 A	-	0.85	-	nC
Gate-Source Charge ^c	Q _{gs}		-	0.1	-	
Gate-Drain Charge ^c	Q _{gd}		-	0.28	-	
Gate Resistance	R _g	f = 1 MHz	-	22	-	Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} = 10 V, I _D = 0.6 A, V _{GS} = 4.5 V, R _g = 10Ω		7		ns
Rise Time	t _r			5		
Turn-Off DelayTime	t _{d(off)}			20		
Fall Time	t _f			8		
Drain-Source Body Diode Ratings and Characteristics ^b (T _C = 25 °C)						
Continuous Source Current	I _S	T _C = 25 °C	-	-	1.8	A
Pulsed Source Current	I _{SM}		-	-	7.2	A
Forward Voltage ^a	V _{SD}	I _S = 0.6 A, V _{GS} = 0 V	-	-	1	V
Reverse Recovery Time	t _{rr}	I _S = 0.6 A, di/dt = 20 A/μs	-	4	-	ns
Reverse Recovery Charge	Q _{rr}		-	1.7	-	nC

Notes

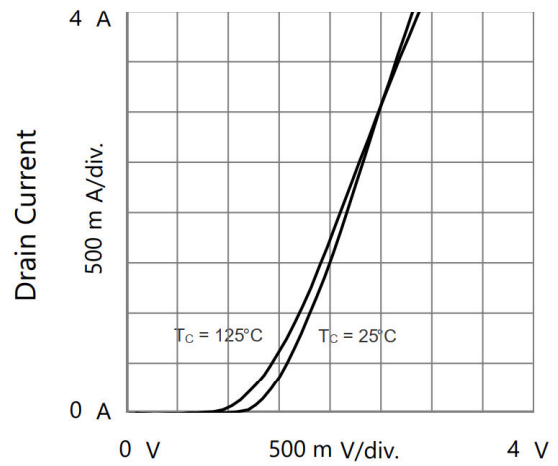
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
 b. Guaranteed by design, not subject to production testing.
 c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

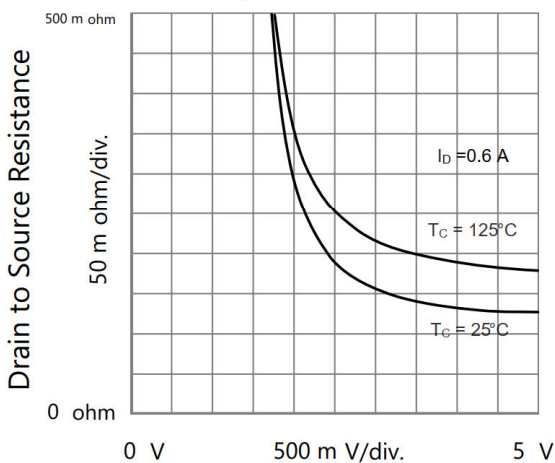
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



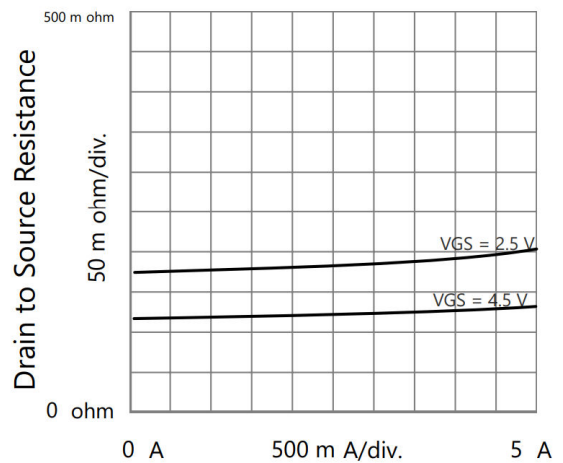
Drain to Source Voltage
Output Characteristics



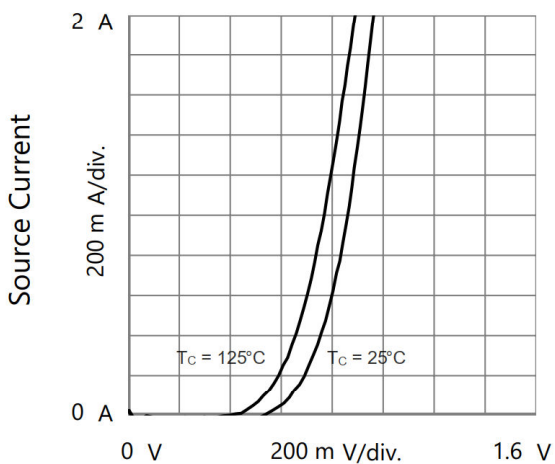
Gate to Source Voltage
Transfer Characteristics



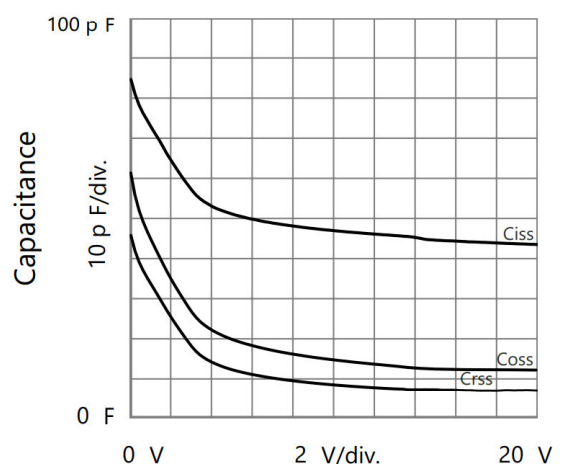
Gate to Source Voltage
Drain to Source Resistance vs. Gate to Source Voltage



Drain Current
Drain to Source Resistance vs. Drain Current

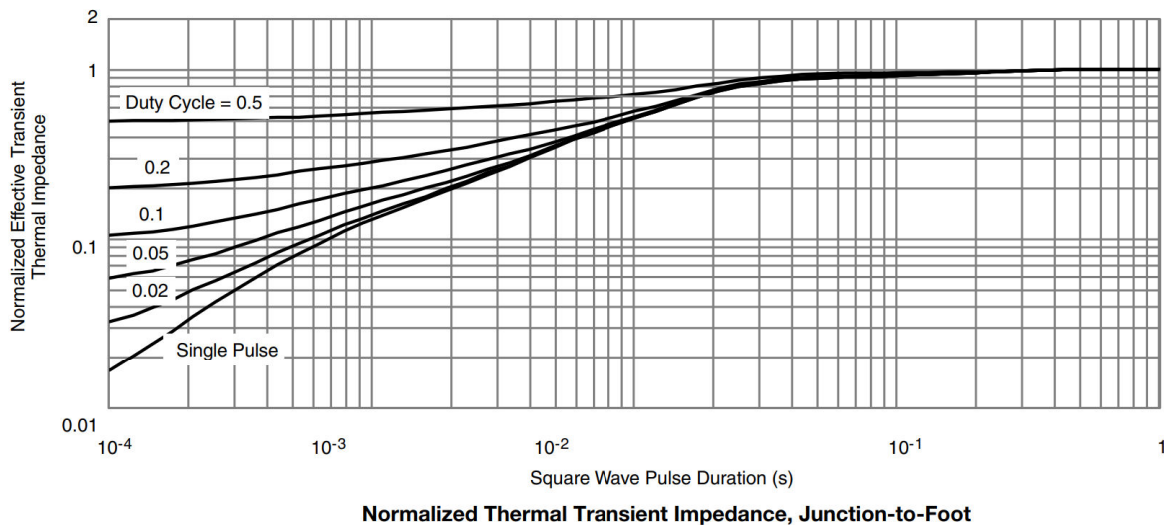
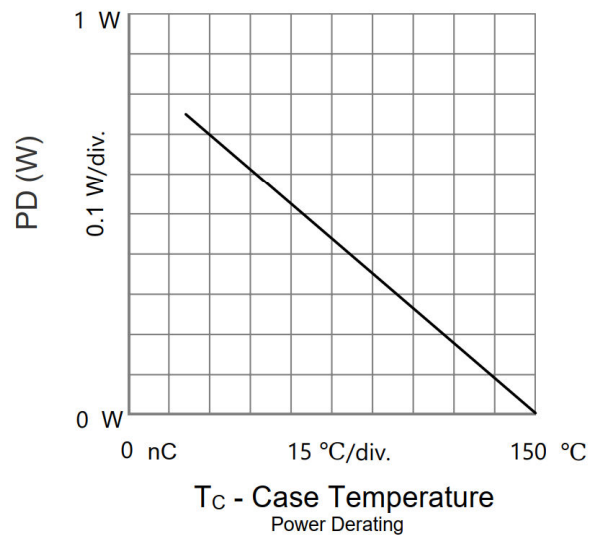
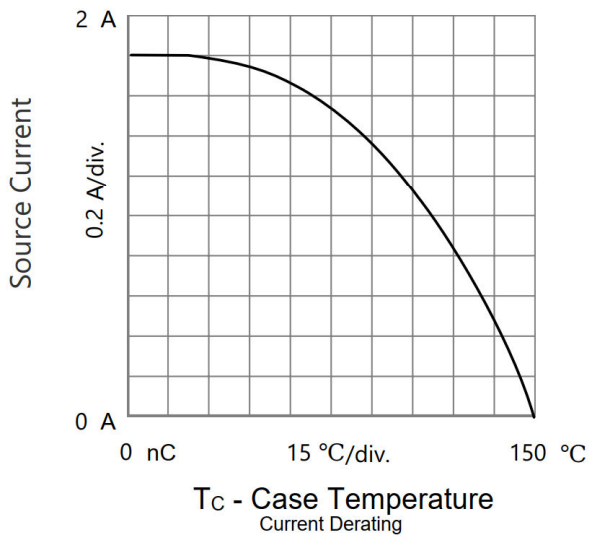
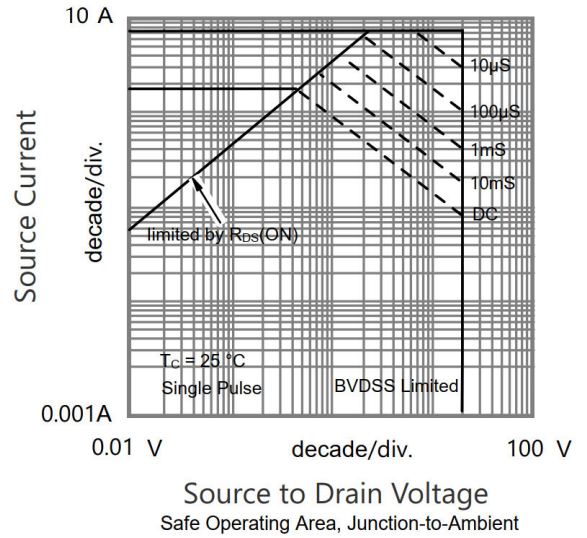
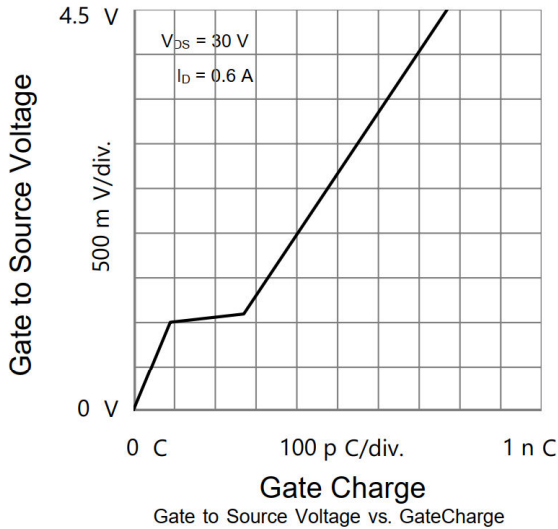


Source to Drain Voltage
Body Diode Forward Characteristics



Drain to Source Voltage
Capacitances

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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